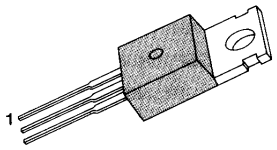
KSD362 NPN EPITAXIAL SILICON TRANSISTOR

B/W TV HORIZONTAL DEFLECTION OUTPUT

- Collector-Base Voltage: V_{CBO}=150V
- Collector Current: I_C=5A
- Collector Dissipation: P_C=40W(T_C=25°C)

TO-220



1.Base 2.Collector 3.Emitter

ABSOLUTE MAXIMUM RATINGS

Characteristic	Symbol	Rating	Unit
Collector-Base Voltage	V_{CBO}	150	V
Collector-Emitter Voltage	V_{CEO}	70	V
Emitter-Base Voltage	V_{EBO}	8	V
Collector Current	I_C	5	A
Collector Dissipation (T_C=25°C)	P_C	40	W
Junction Temperature	T_J	150	°C
Storage Temperature	T_{STG}	-55 ~ 150	°C

ELECTRICAL CHARACTERISTICS (T_C =25°C)

Characteristic	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector-Base Breakdown Voltage	BV_{CBO}	I_C = 1mA, I_E = 0	150			V
Collector-Emitter Breakdown Voltage	BV_{CEO}	I_C = 2mA, R_{BE} = ∞	70			V
Emitter-Base Breakdown Voltage	BV_{EBO}	I_E = 1mA, I_C = 0	8			V
Collector Cutoff Current	I_{CBO}	V_{CB} = 100V, I_E = 0			20	μA
DC Current Gain	h_{FE}	V_{CE} = 5V, I_C = 5A	20		140	
Collector-Emitter Saturation Voltage	V_{CE}(sat)	I_C = 5A, I_B = 0.5A			1	V
Base-Emitter Saturation Voltage	V_{BE}(sat)	I_C = 5A, I_B = 0.5A			1.5	V
Current Gain Bandwidth Product	f_T	V_{CE} = 5V, I_C = 0.5A		10		MHz

h_{FE} CLASSIFICATION

Classification	N	R	O
h_{FE}	20 - 50	40 - 80	70 - 140

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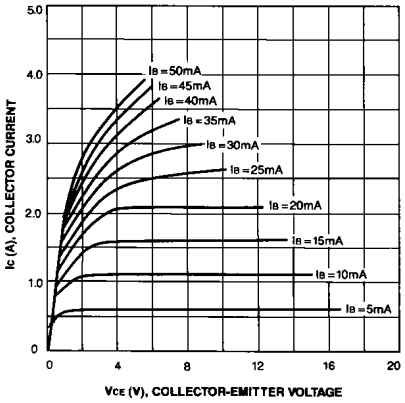
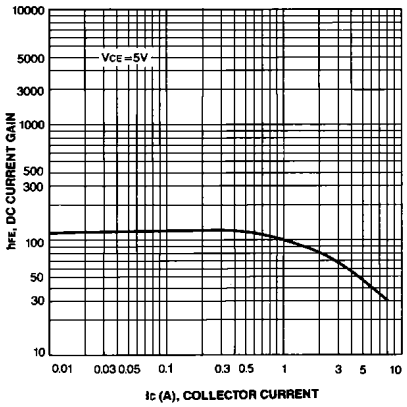
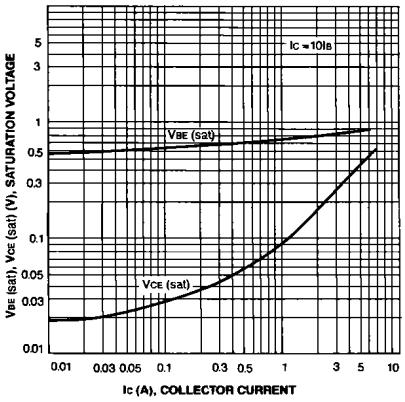
STATIC CHARACTERISTIC



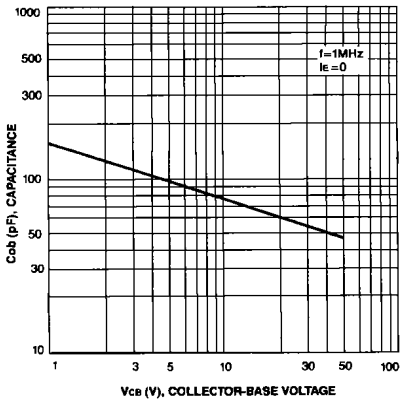
DC CURRENT GAIN



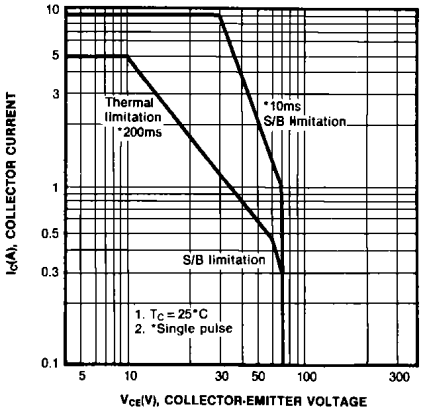
BASE-EMITTER SATURATION VOLTAGE
COLLECTOR-EMITTER SATURATION VOLTAGE



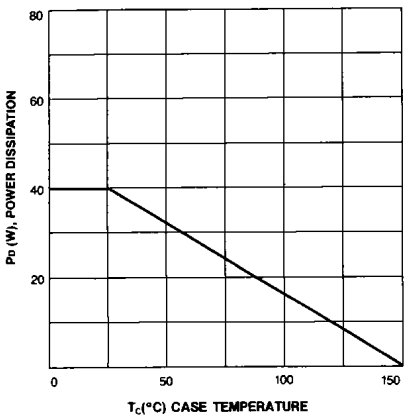
COLLECTOR OUTPUT CAPACITANCE



SAFE OPERATING AREA



POWER DERATING



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